



INVESTOR MEETING 2014

William Holt

Executive Vice President
General Manager, Technology and Manufacturing Group

Key Messages from 2013

Intel Continues to Deliver the Benefits of Moore's Law



True Cost Reduction Remains Possible in a Capital Intensive Environment



The Benefits of Technology Apply Across the Product Portfolio



14nm Status - 2013

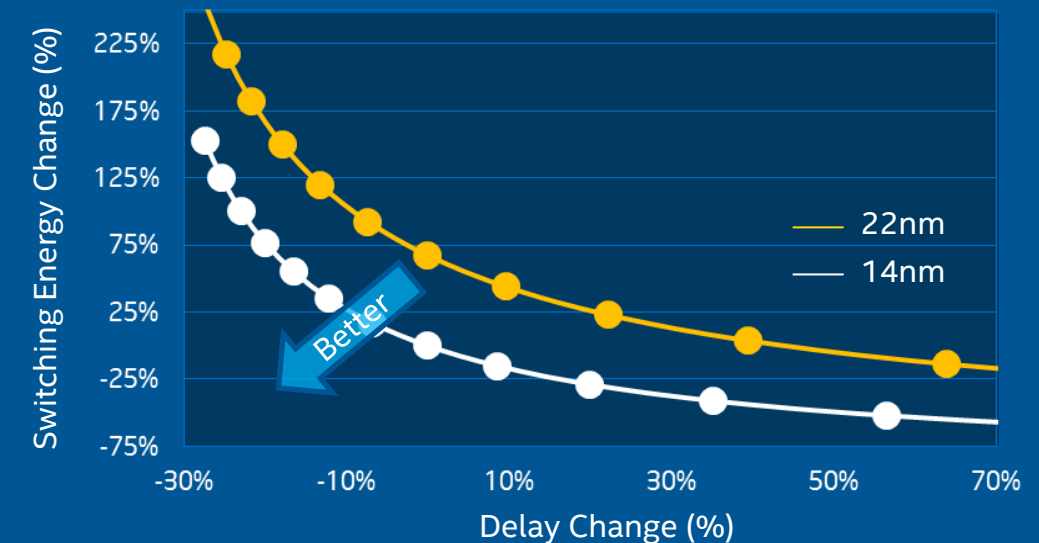
Yield

at the same point in development



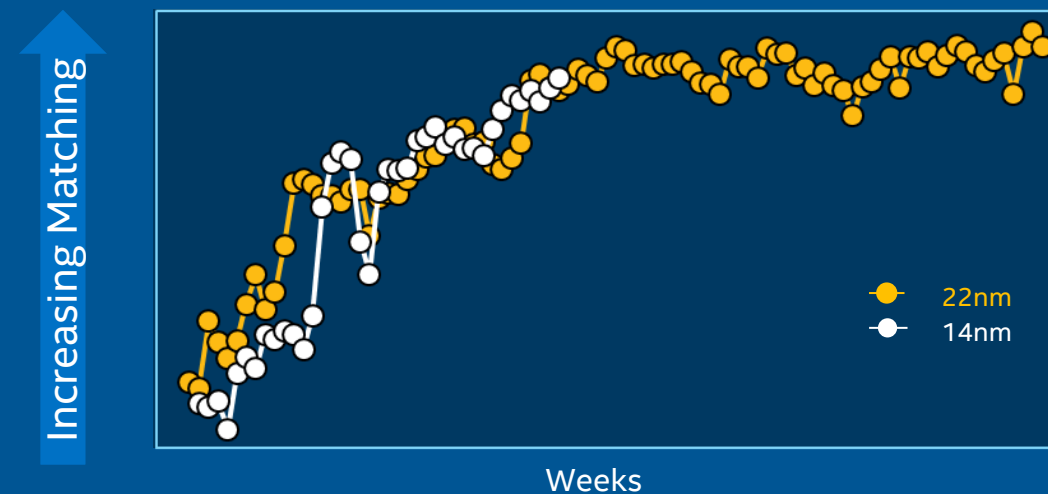
Performance Improvement

Switching Energy vs. Gate Delay



Key Parameter Matching

% of key process parameters meeting 3-sigma targets at the same point in development



Reliability Scorecard

at the same point in development

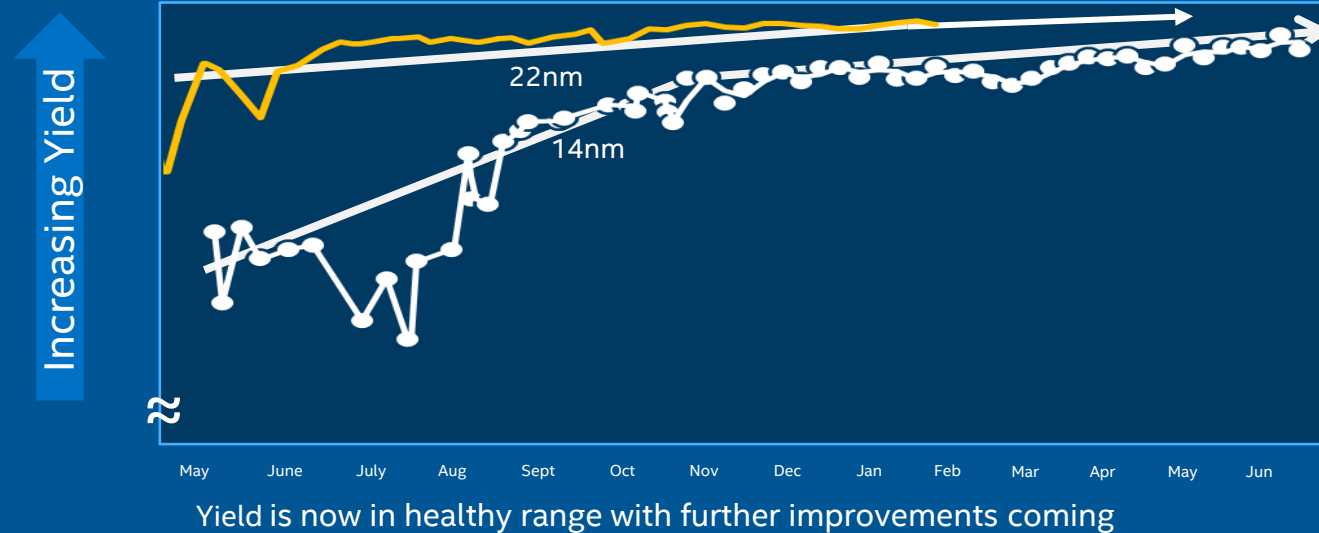
Module	22nm (2 year offset)	14nm	
Transistor	Low risk	Low risk	Meeting all cert goals
Interconnect	Low risk	Low risk	Meeting all cert goals
Thermo-Mechanical/Moisture	Medium risk	Low risk	Close to meeting goals
Test Vehicle Yield	Medium risk	High risk	Not yet meeting all goals, needs additional work
ESD/LU	Low risk	Low risk	Meeting all cert goals
Alpha Particle/Soft Error	Medium risk	Low risk	Close to meeting goals

Generally healthy reliability at this stage, on track for Q1 '14 certification *

14nm Status - 2014

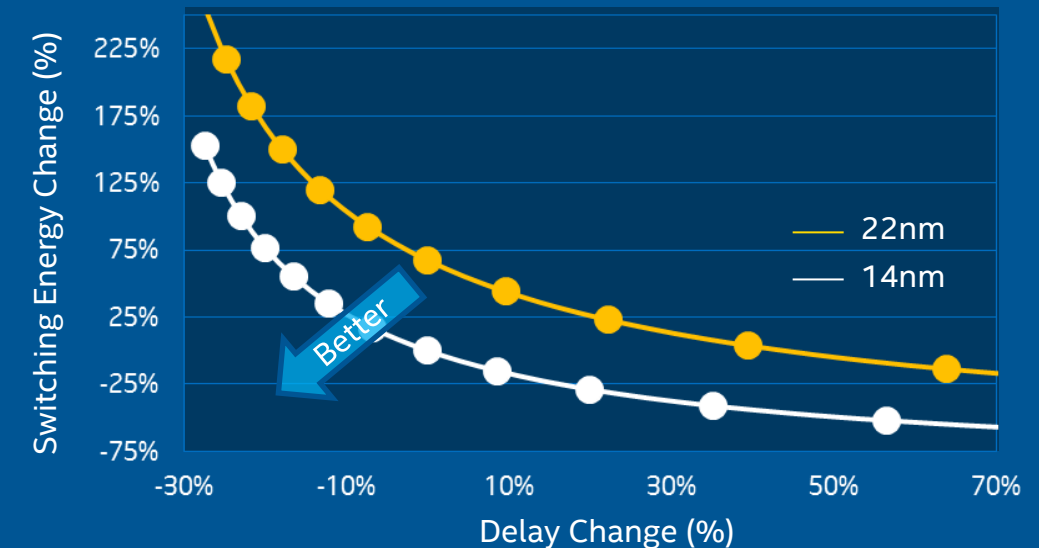
Yield

at the same point in development



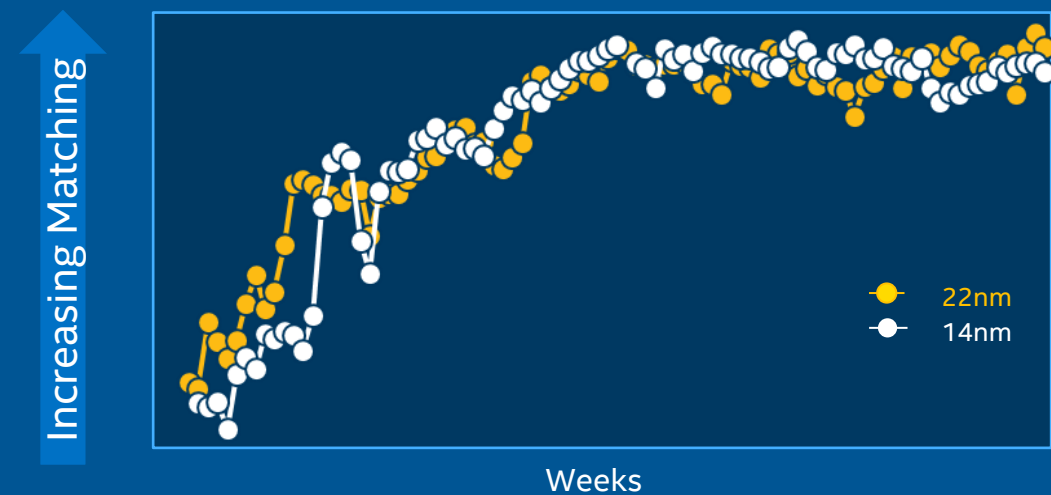
Performance Improvement

Switching Energy vs. Gate Delay



Key Parameter Matching

% of key process parameters meeting 3-sigma targets at the same point in development



14 nm key process parameter matching on track with 22 nm trend

Reliability Scorecard

at the same point in development

Module

Transistor
Interconnect
Thermo-Mechanical/Moisture
Test Vehicle Yield
ESD/LU
Alpha Particle/Soft Error

22nm
(2 year offset)

14nm

Transistor	Low risk	Low risk
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Thermo-Mechanical/Moisture	Low risk	Low risk
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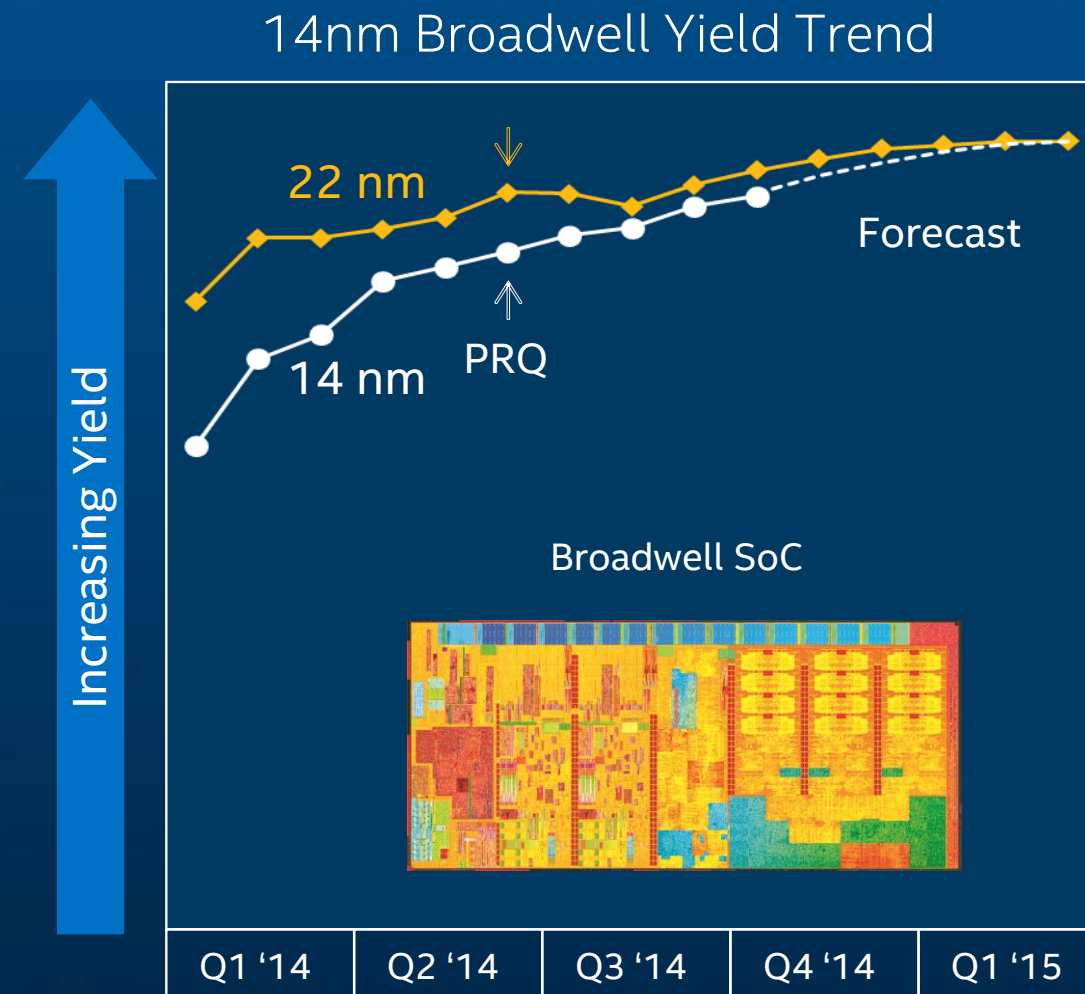
Low risk
Meeting all cert goals

Medium risk
Close to meeting goals

High risk
Not yet meeting all goals, needs additional work

14nm PRQ achieved Q2 2014

14 nm Product Yield Is In Healthy Range



22 nm data are shifted to align date of lead product qual
Depicts relative health, lines not to scale

22nm Is Intel's Highest Yielding Process Ever

14nm Technology Overview

A True 14 nm Technology

2nd Generation FinFET

52 nm Interconnect Pitch

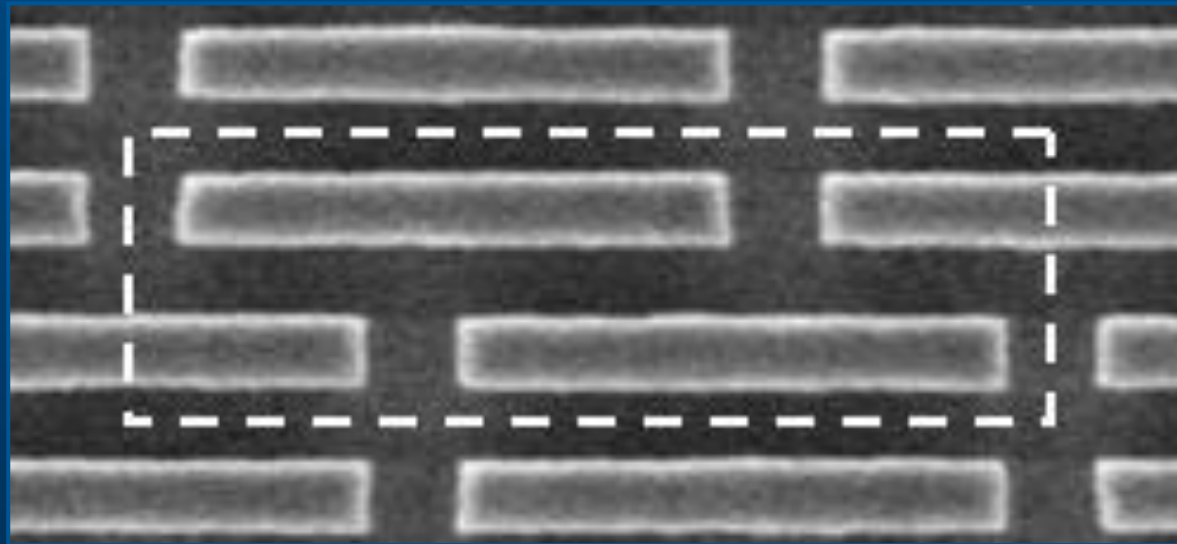
First Use of Air Gaps

Intel Has Developed a True 14 nm Technology

	22 nm Node	14 nm Node	Scale
Transistor Fin Pitch	60	42	.70x
Transistor Gate Pitch	90	70	.78x
Interconnect Pitch	80 nm	52 nm	.65x

SRAM Memory Cells

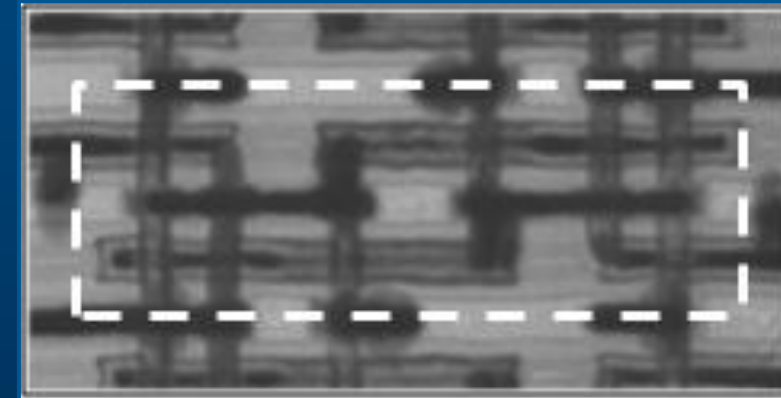
22 nm Process



.108 μm^2

(Used on CPU products)

14 nm Process

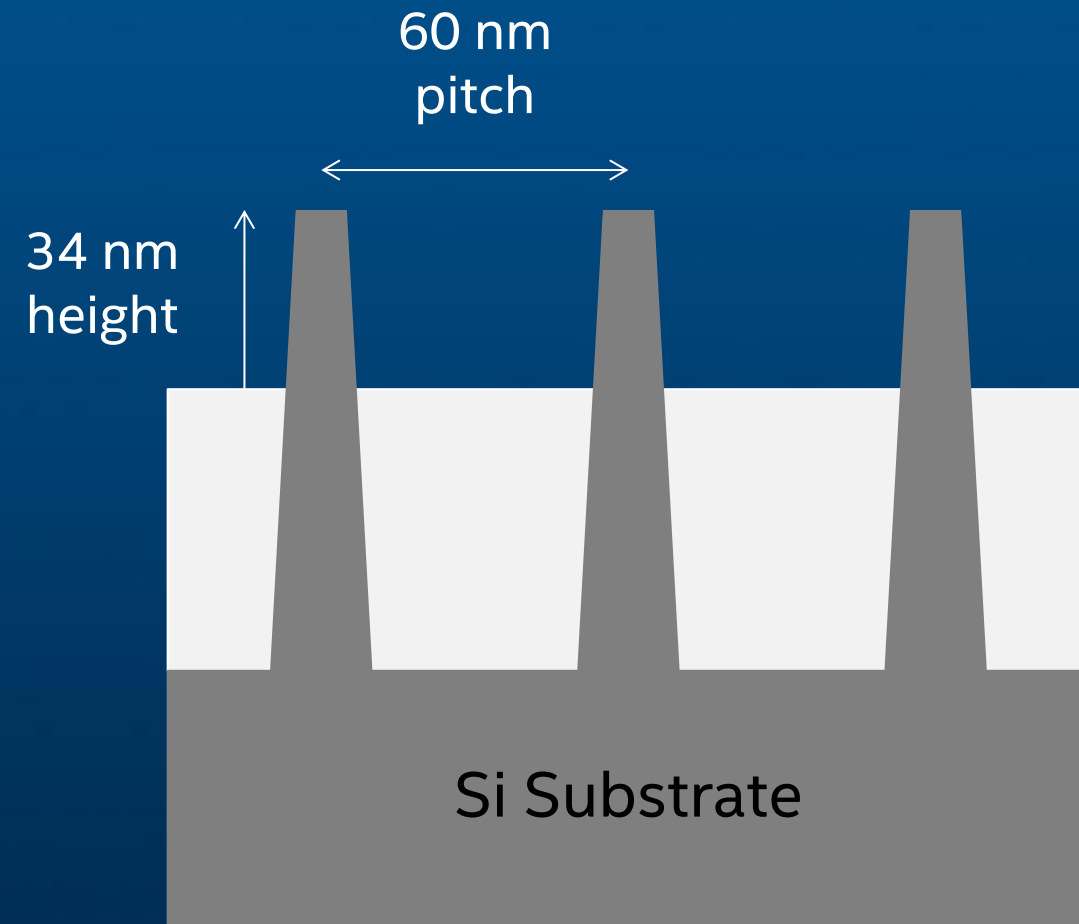


.0588 μm^2

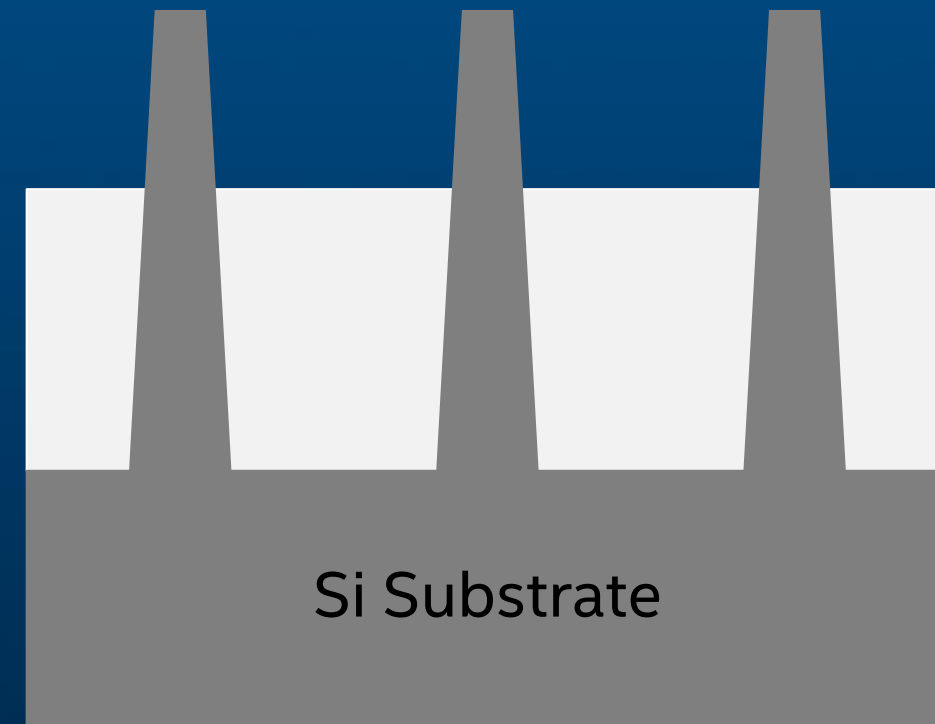
(0.54x area scaling)

14 nm Design Rules + 2nd Generation Tri-gate Transistor Provides Industry-leading SRAM Density

Transistor Fin Improvement

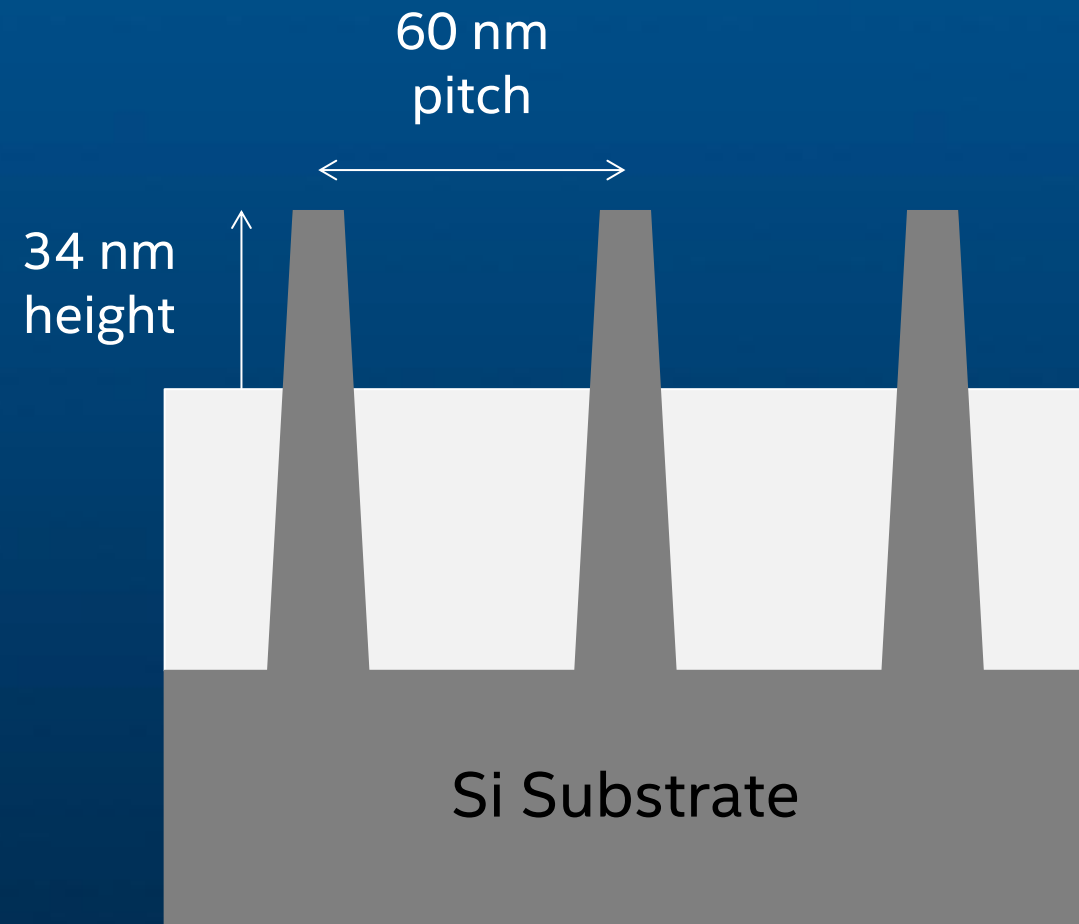


22 nm Process

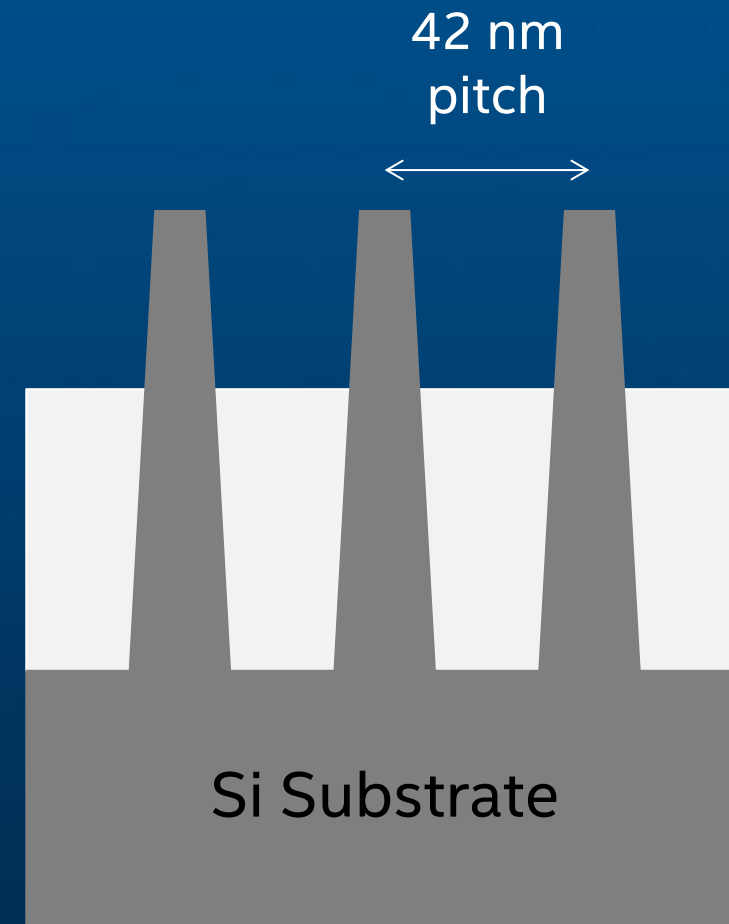


14 nm Process

Transistor Fin Improvement



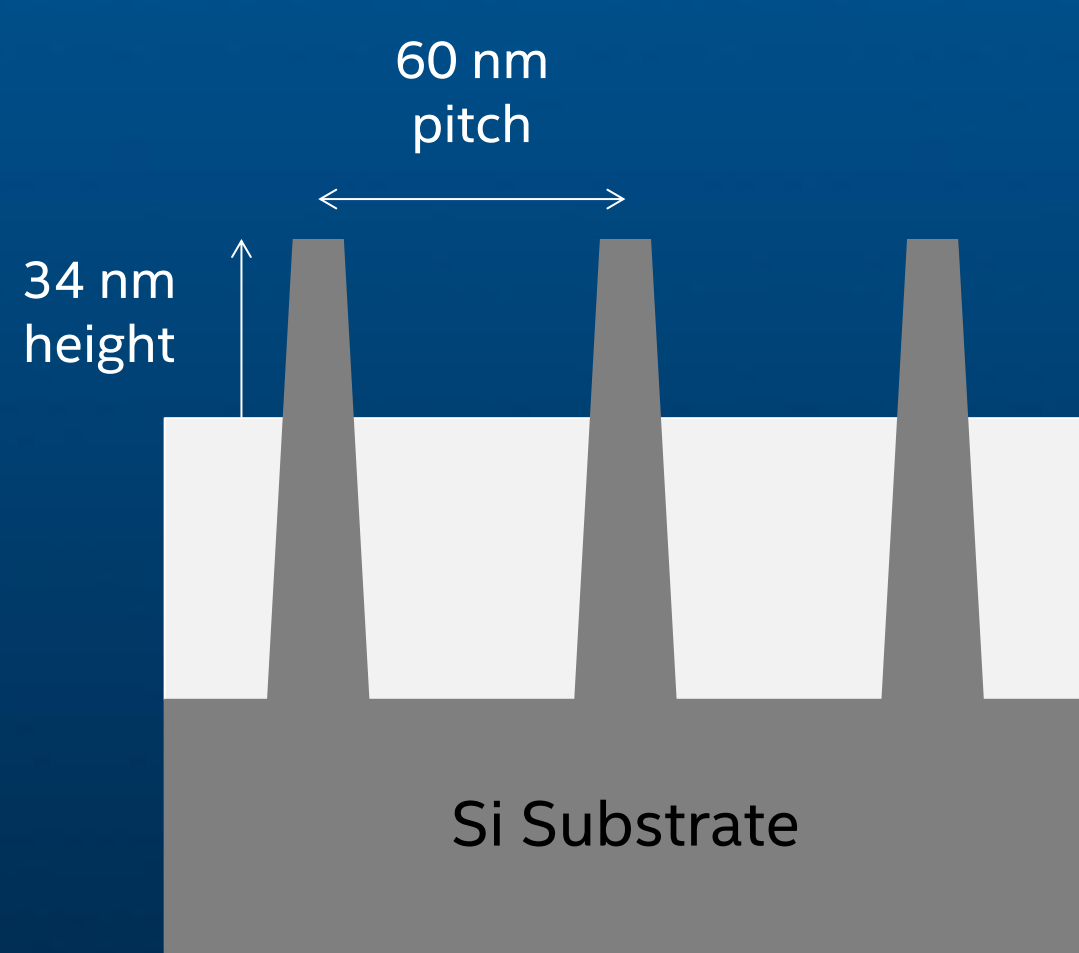
22 nm Process



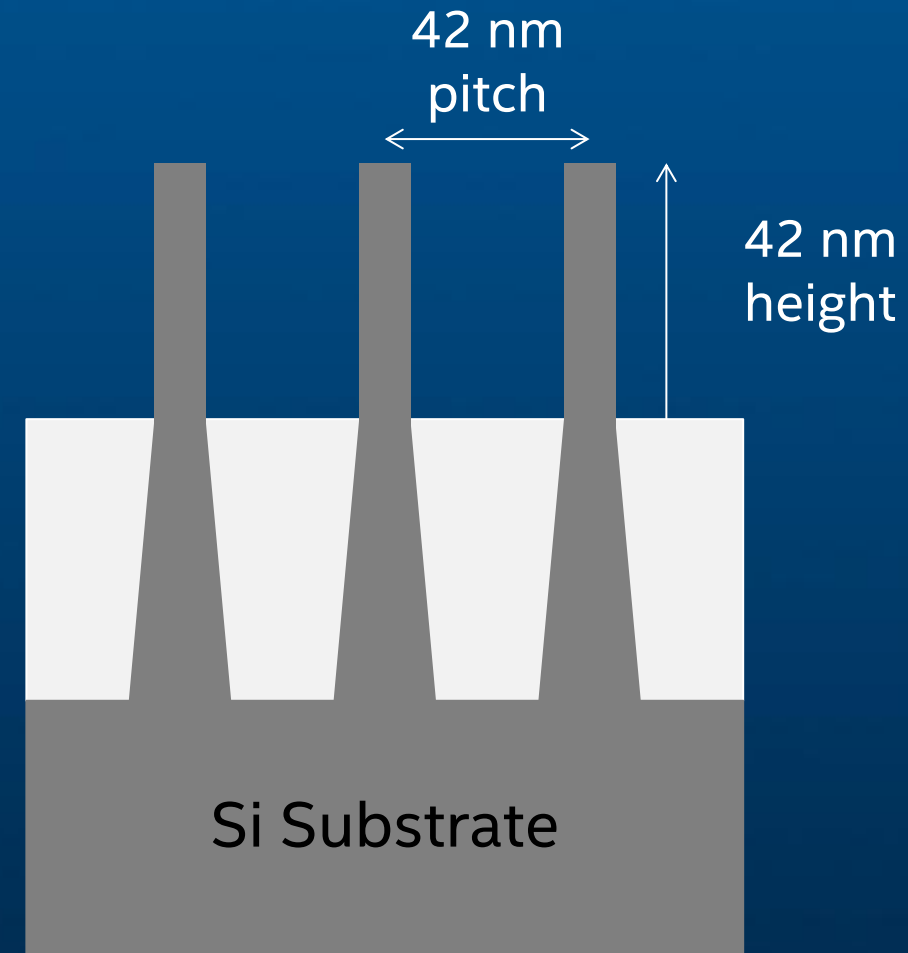
14 nm Process

Tighter Fin Pitch for Improved Density

Transistor Fin Improvement



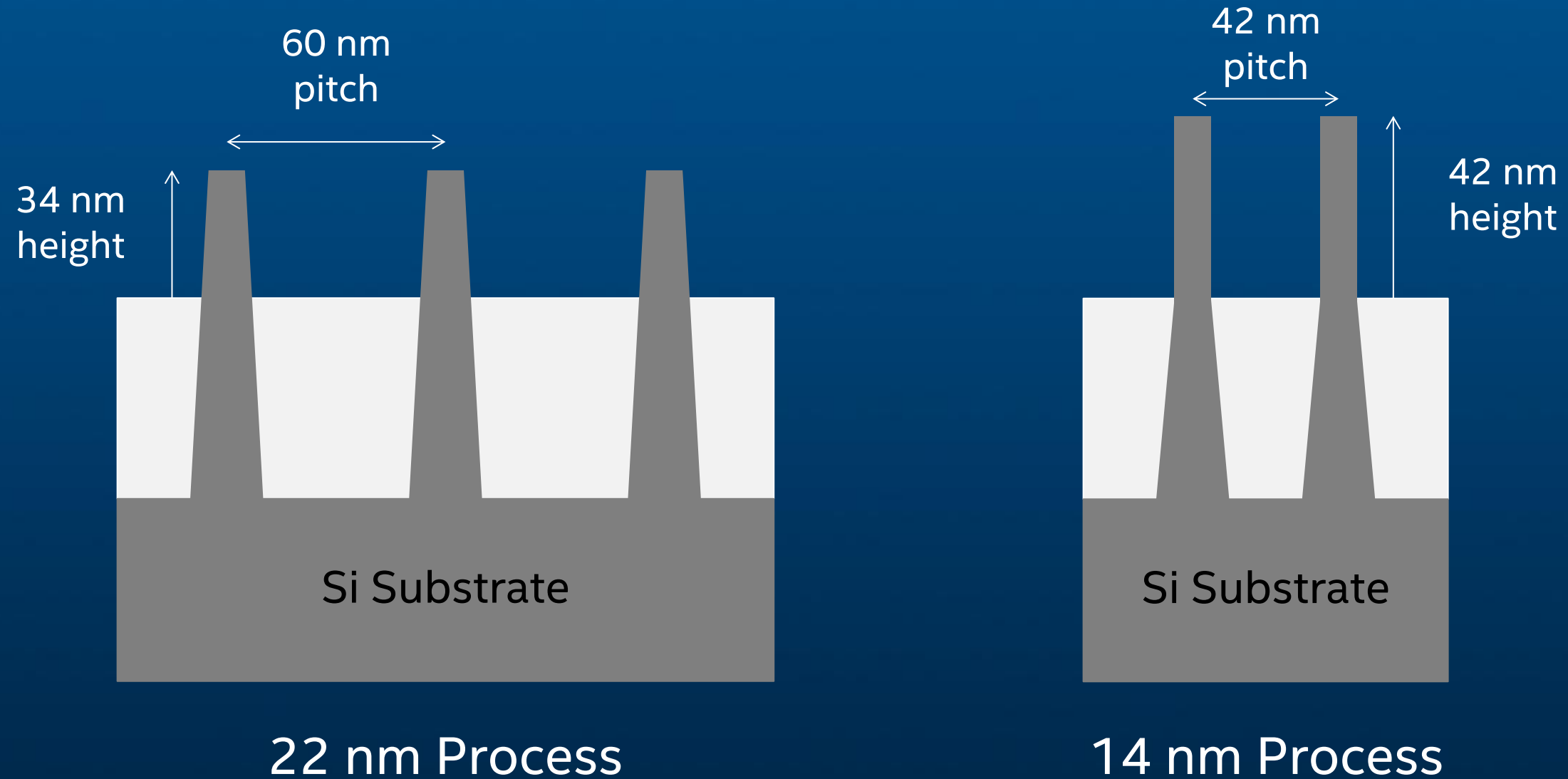
22 nm Process



14 nm Process

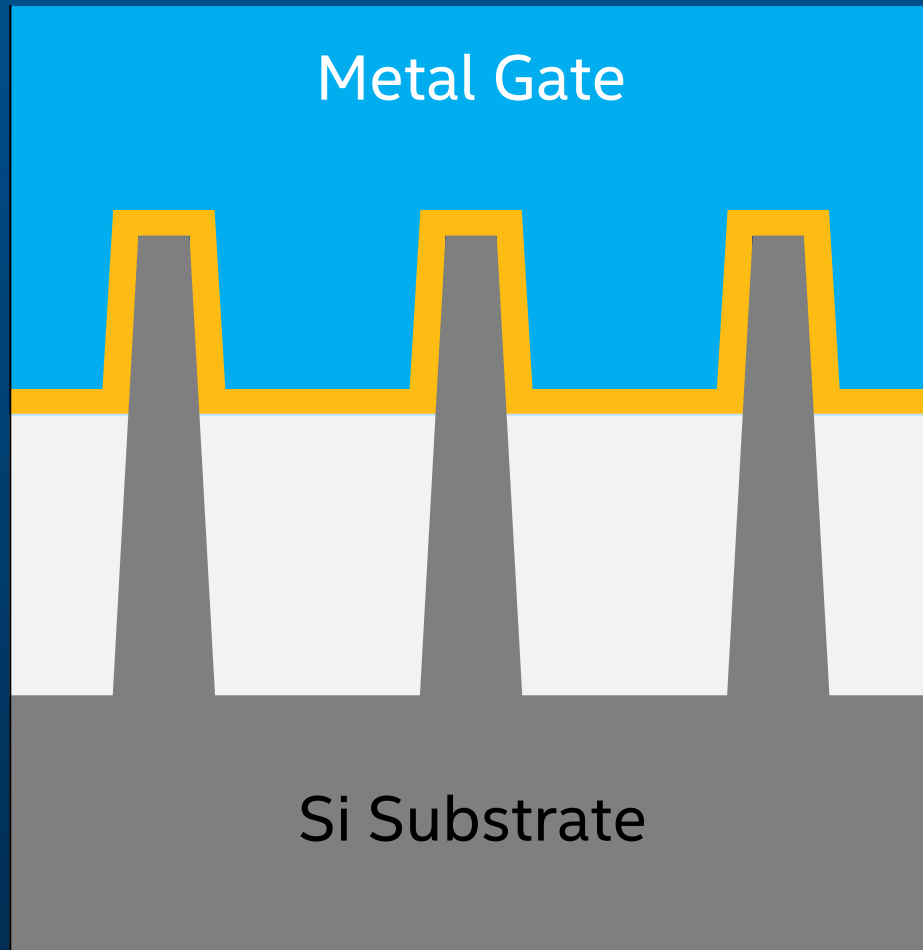
Taller and Thinner Fins for Increased Drive Current and Performance

Transistor Fin Improvement

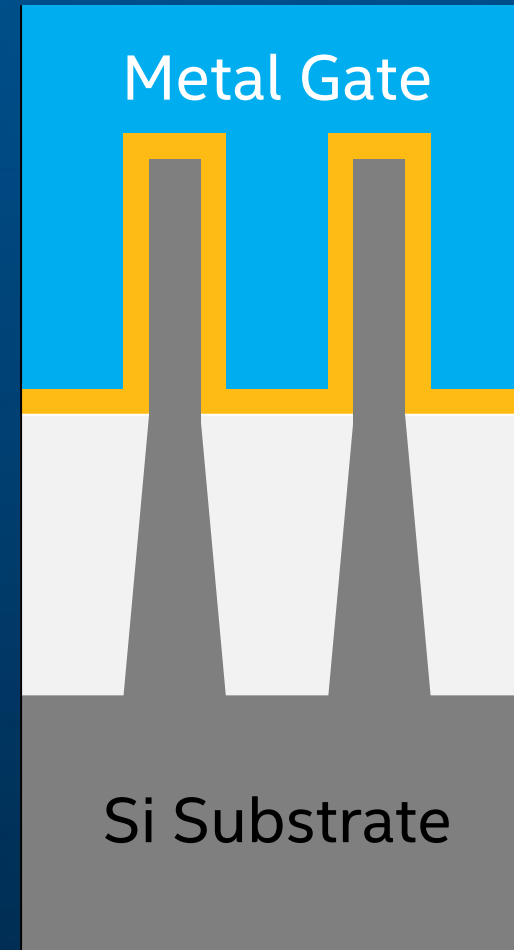


***Reduced Number of Fins for Improved Density
and Lower Capacitance***

Transistor Fin Improvement

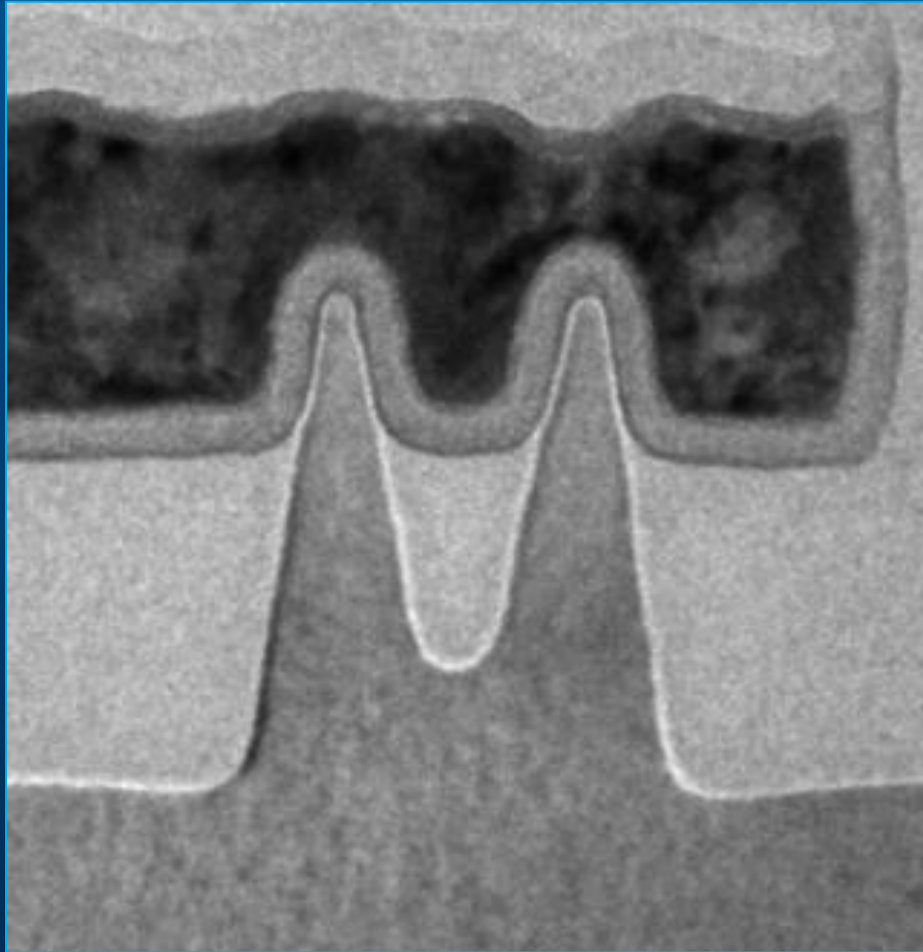


22 nm 1st Generation
Tri-gate Transistor

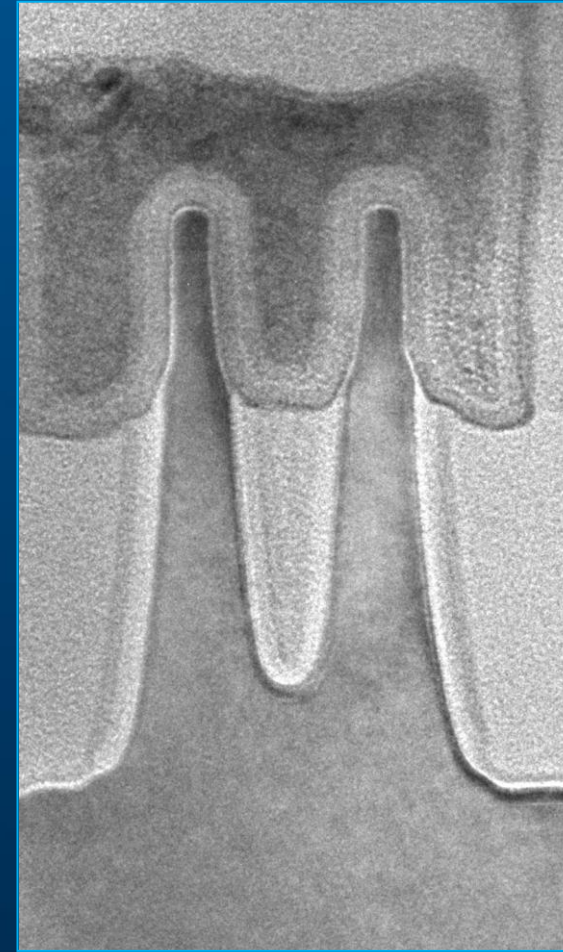


14 nm 2nd Generation
Tri-gate Transistor

Transistor Fin Improvement

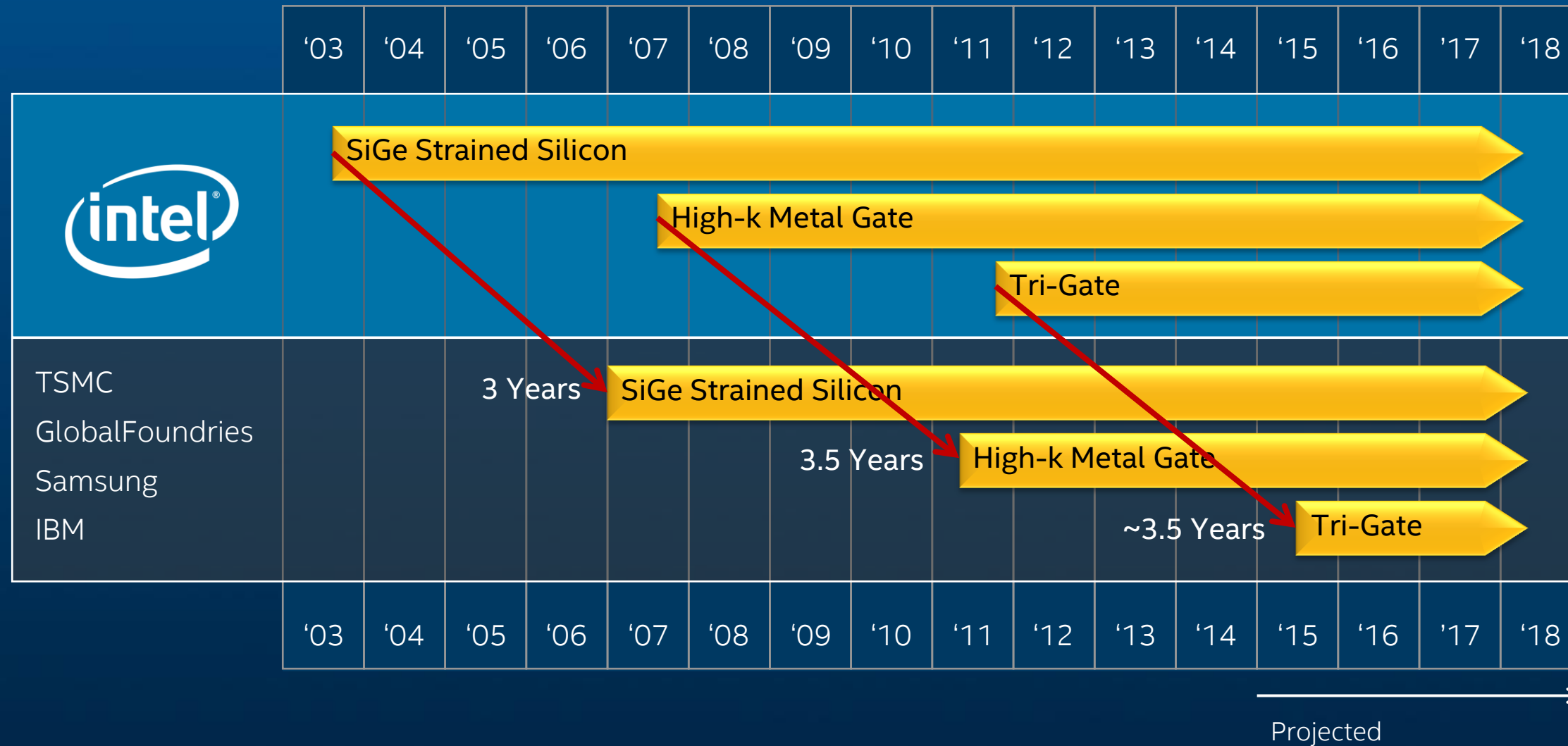


22 nm 1st Generation
Tri-gate Transistor

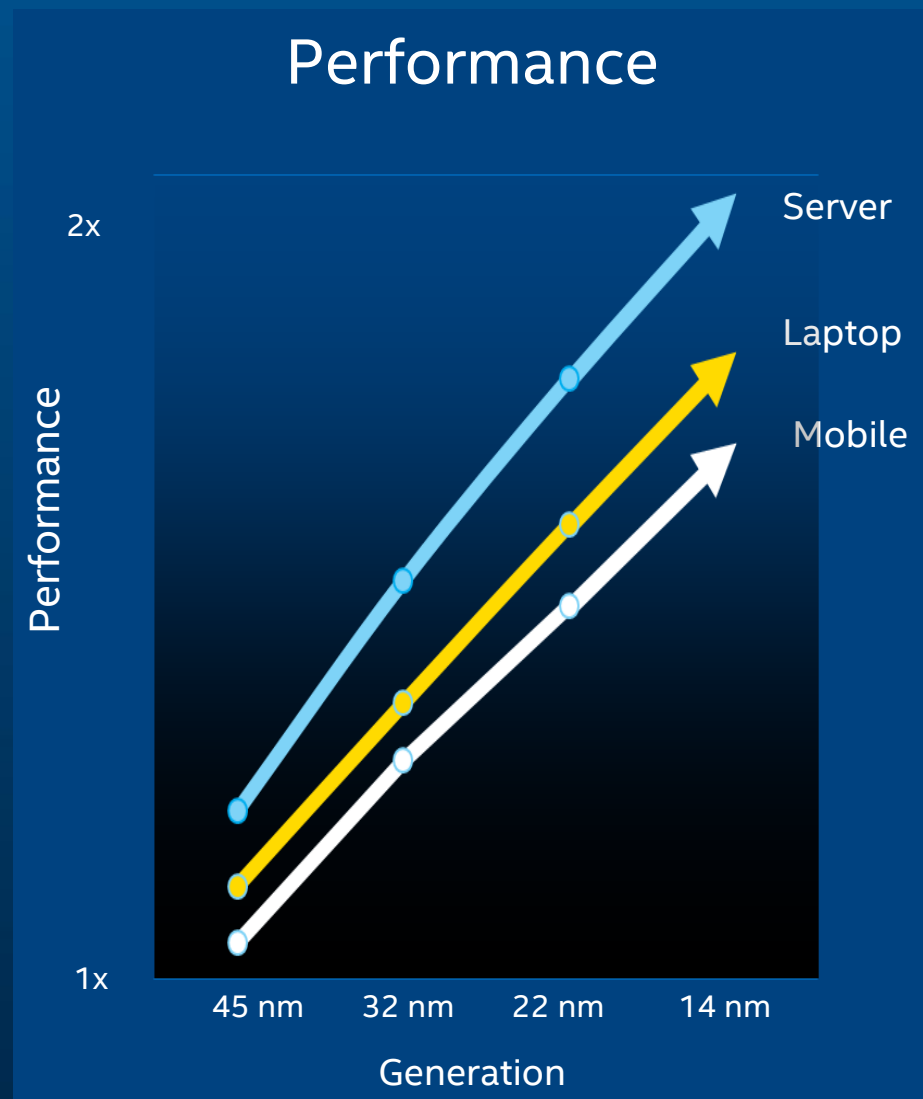


14 nm 2nd Generation
Tri-gate Transistor

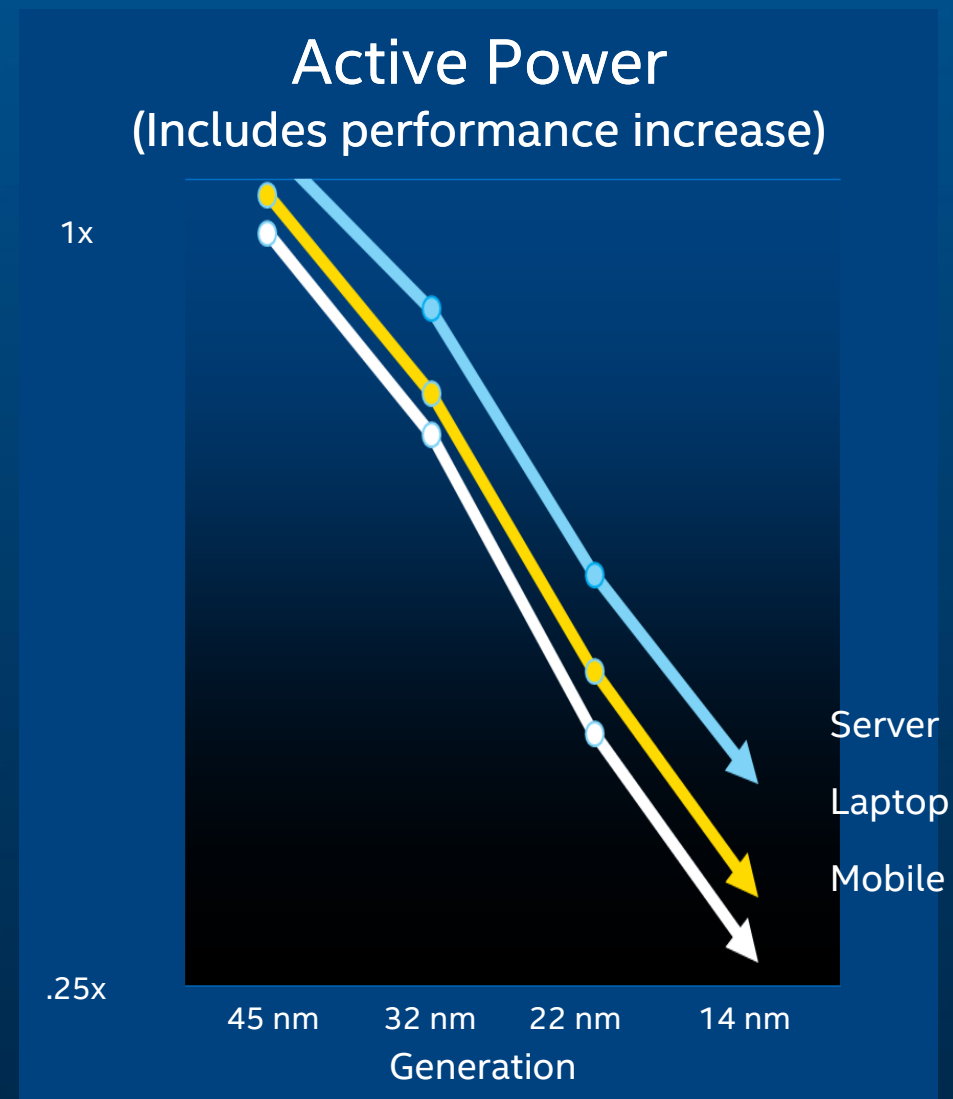
Intel Transistor Leadership



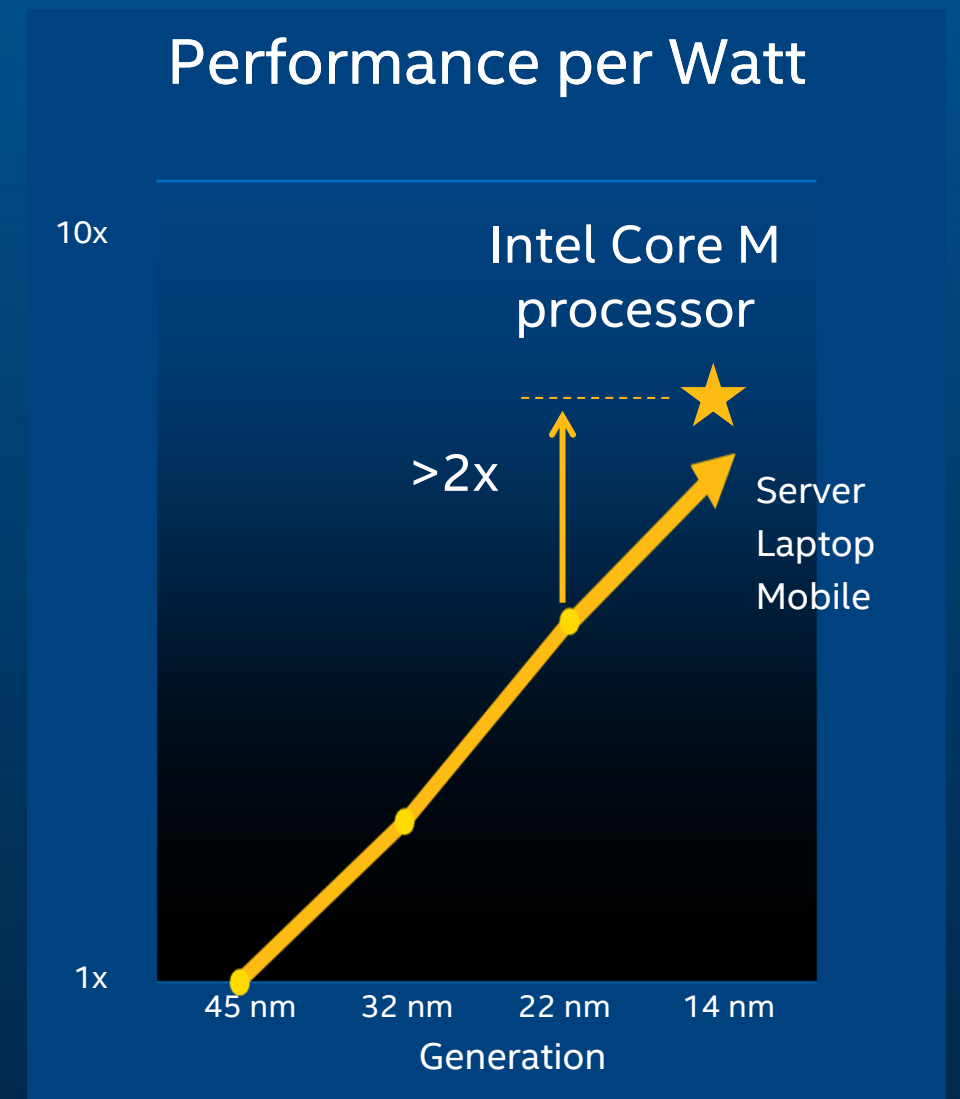
2nd Generation Tri-Gate is the Critical Enabler



Performance Improved



Active Power Reduced

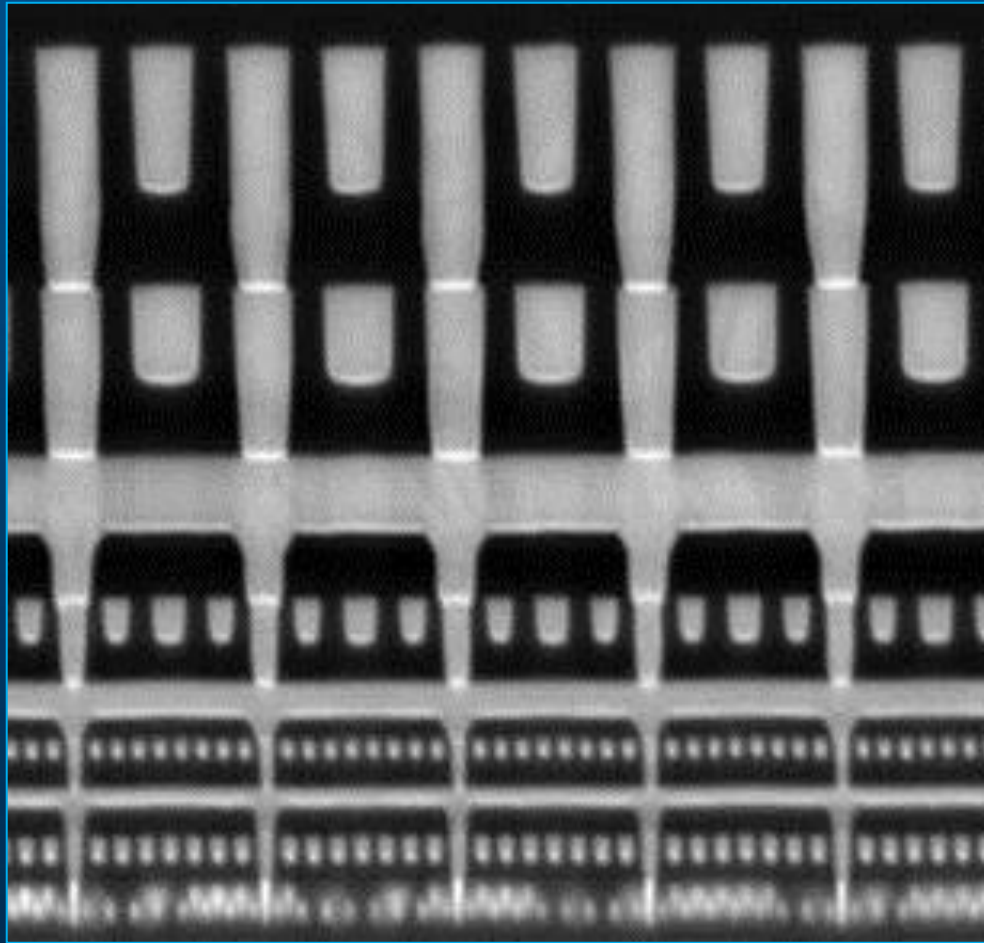


Performance per Watt Improves

14 nm BDW-Y Delivers >2x Improvement in Performance per Watt

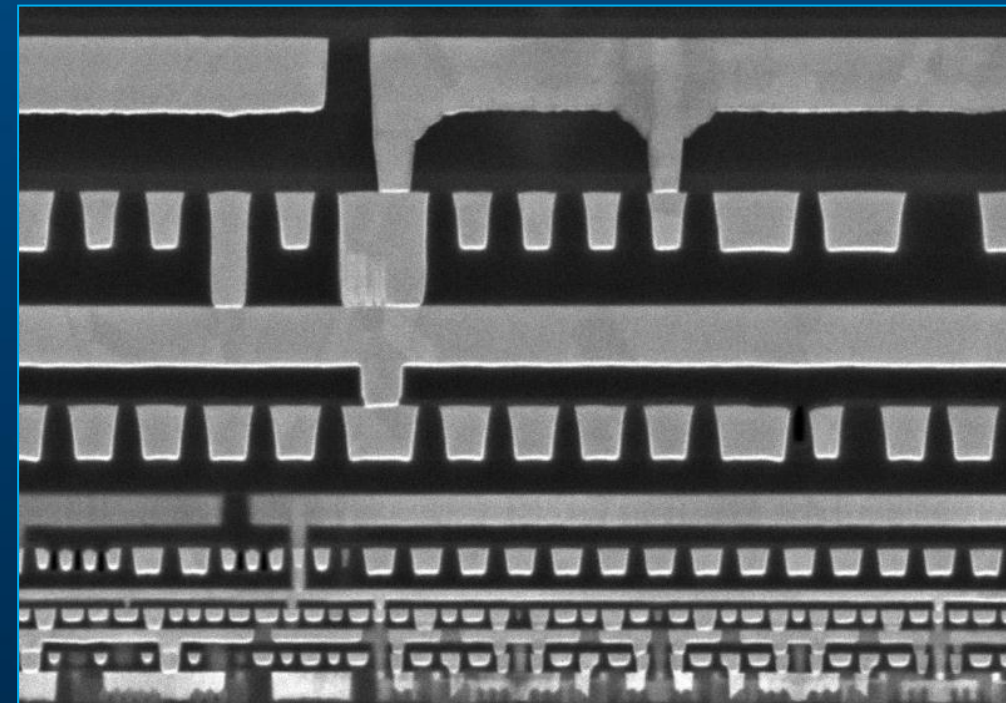
Interconnects

22 nm Process



80 nm minimum pitch

14 nm Process

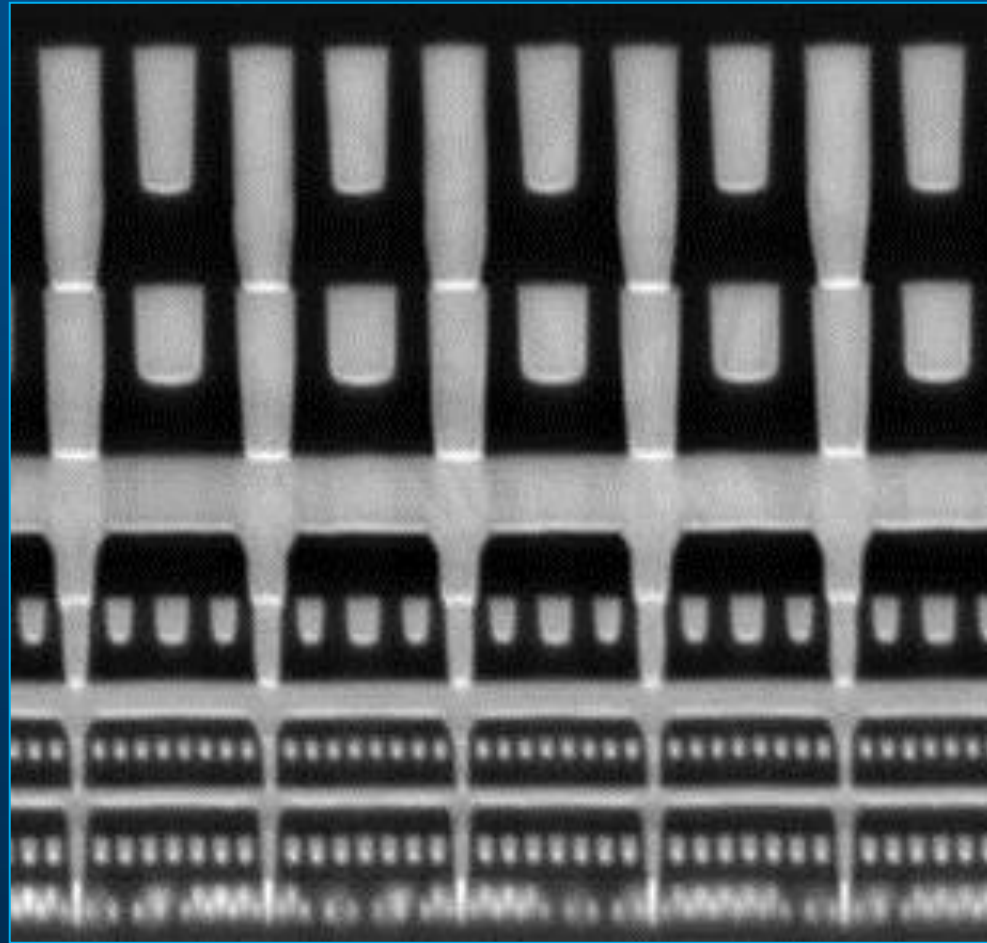


52 nm (0.65x) minimum pitch

52 nm Interconnect Pitch Provides Better-than-normal Interconnect Scaling

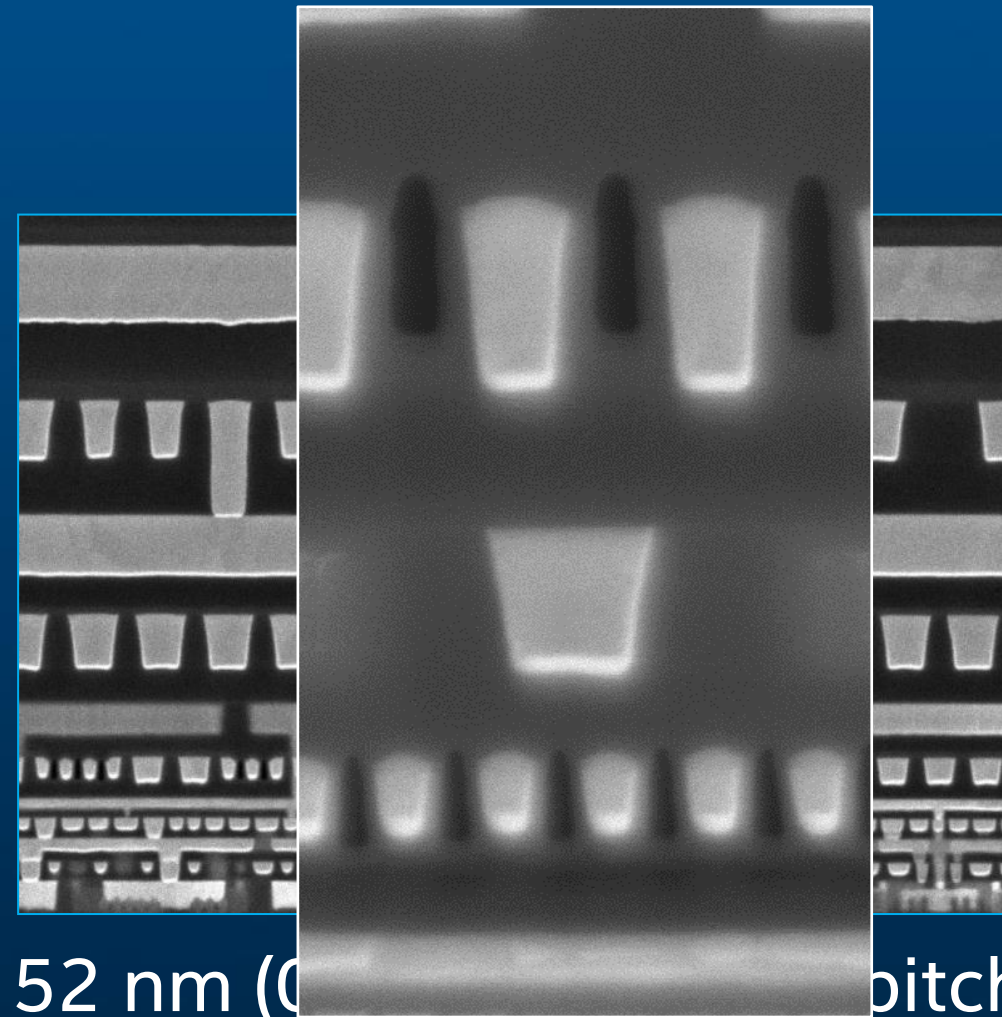
Interconnects

22 nm Process



80 nm minimum pitch

14 nm Process

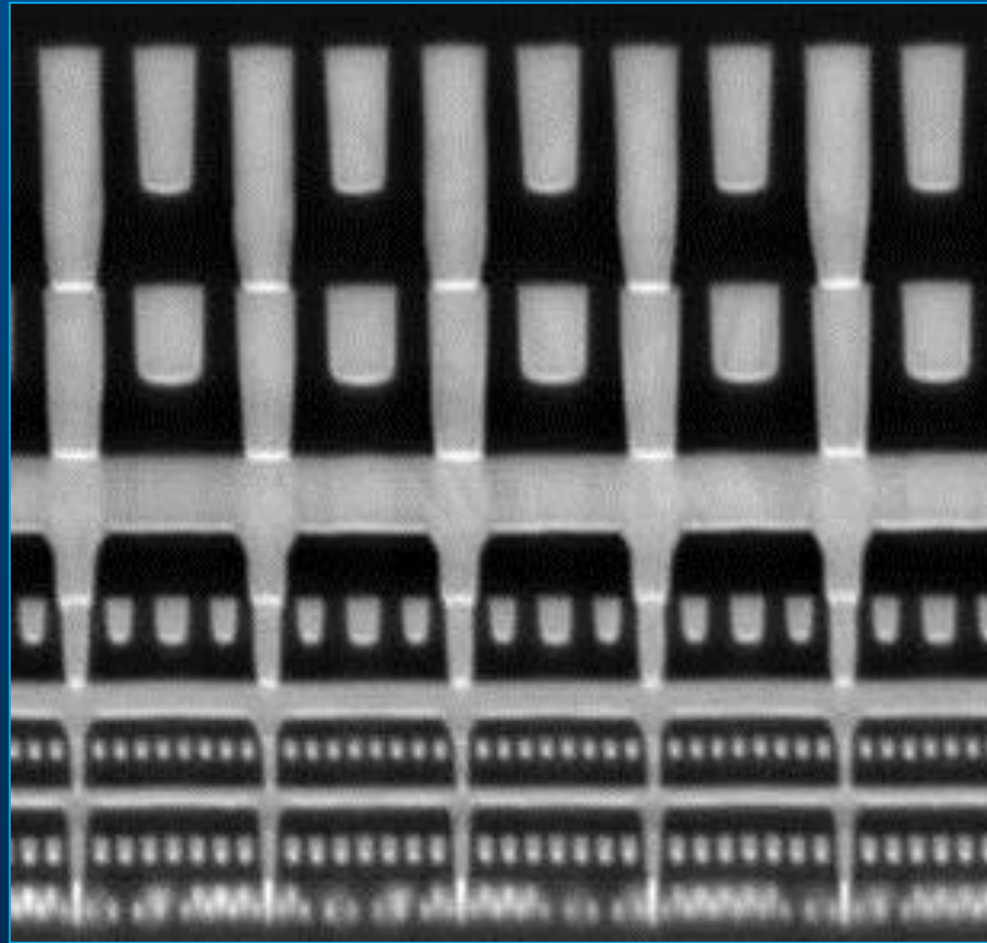


52 nm (0.12 μm) pitch

52 nm Interconnect Pitch Provides Better-than-normal Interconnect Scaling

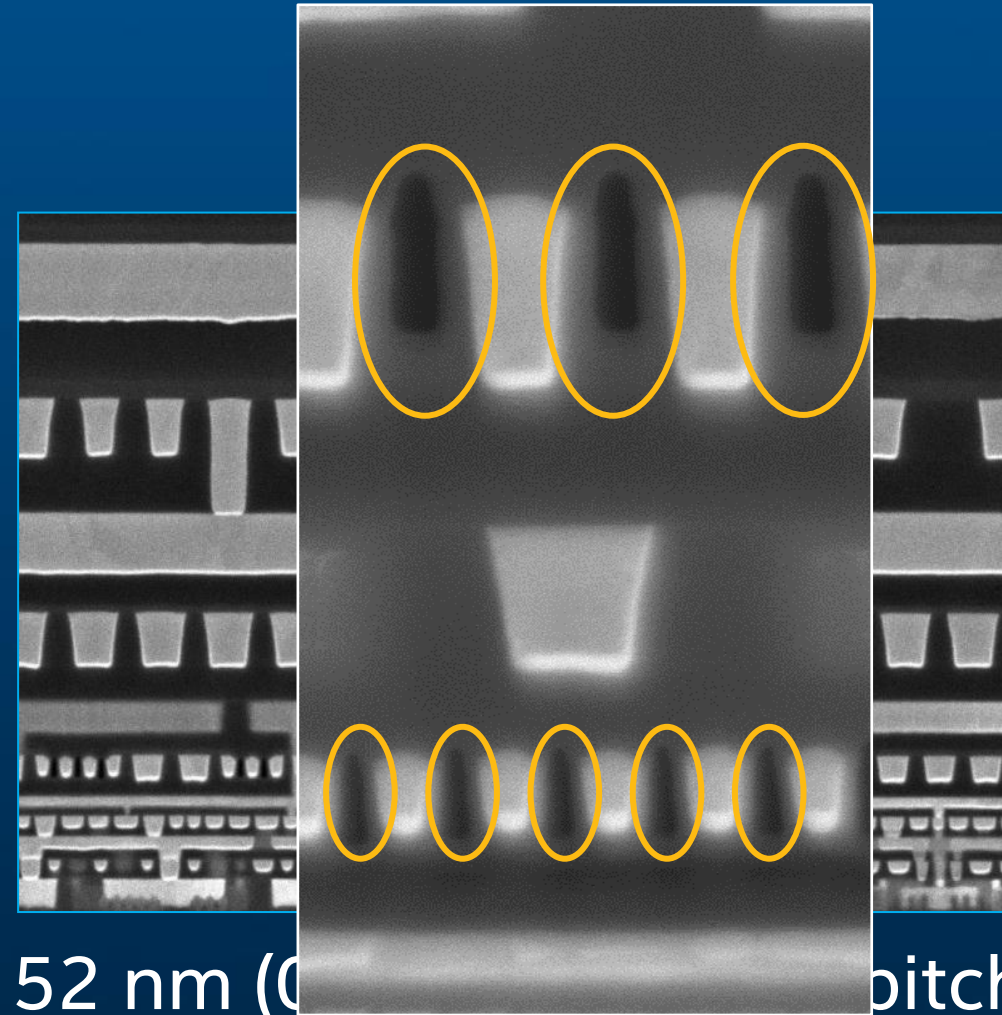
Interconnects

22 nm Process



80 nm minimum pitch

14 nm Process



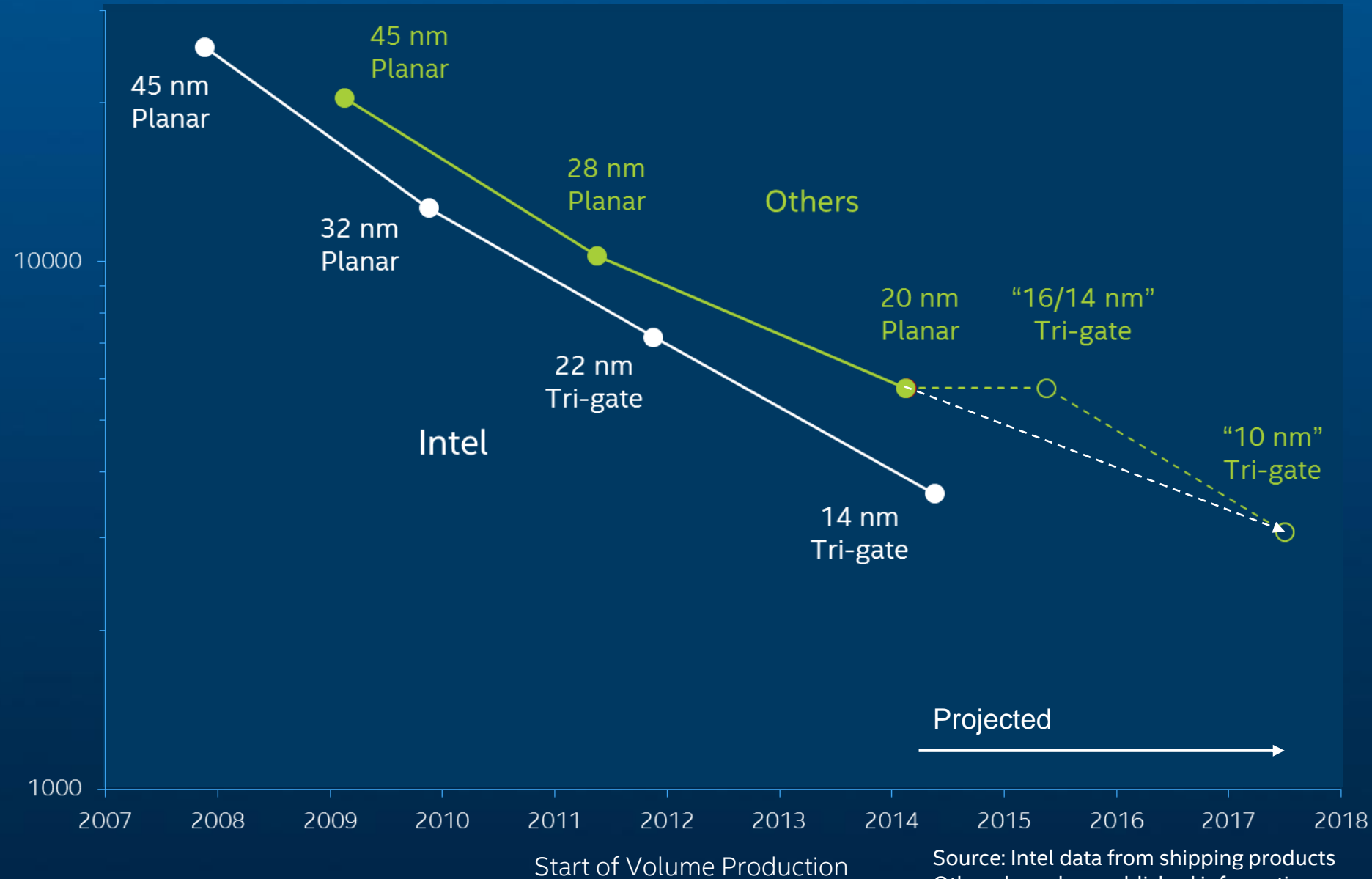
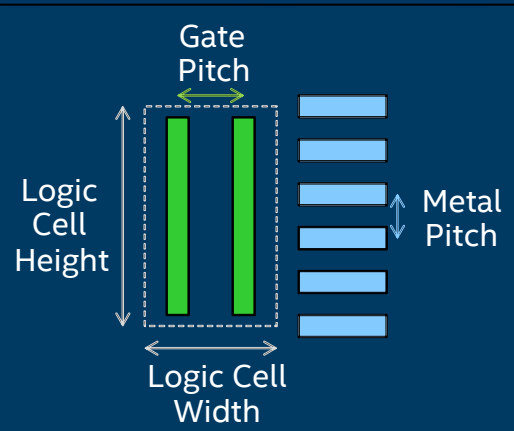
52 nm (0.15 μm) pitch

***52 nm Interconnect Pitch Provides Better-than-normal Interconnect Scaling
First Use of Air Gaps to Improve Interconnect Performance***

Logic Area Scaling Trend

(Publicly available scaling information)

Gate Pitch
x
Metal Pitch
(nm²)

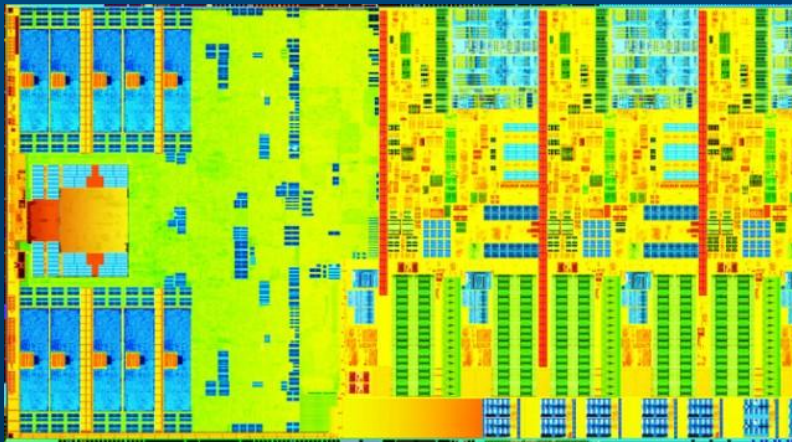


Source: Intel data from shipping products
Others based on published information:
45nm: K-L Cheng (TSMC), 2007 IEDM, p. 243
28nm: F. Arnaud (IBM alliance), 2009 IEDM, p. 651
20nm: H. Shang (IBM alliance), 2012 VLSI, p.129
16nm: S. Wu (TSMC), 2013 IEDM, p. 224
10nm: K-I Seo (IBM alliance), 2014 VLSI, p. 14

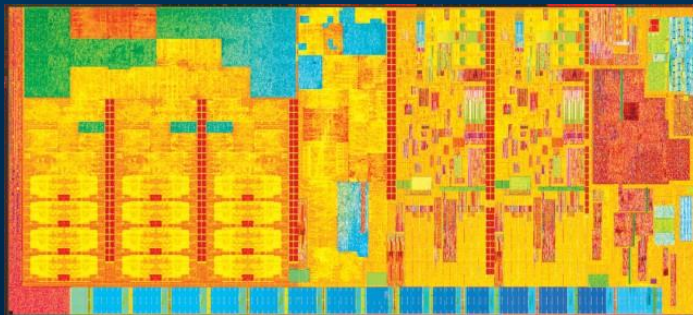
14nm Enables Cost and Performance Benefits

Haswell 2 X 2 (22nm)

960M Transistors



**35%
More
Transistors**



**37%
Smaller**

Broadwell 2 X 2 (14nm)

1.3B transistors

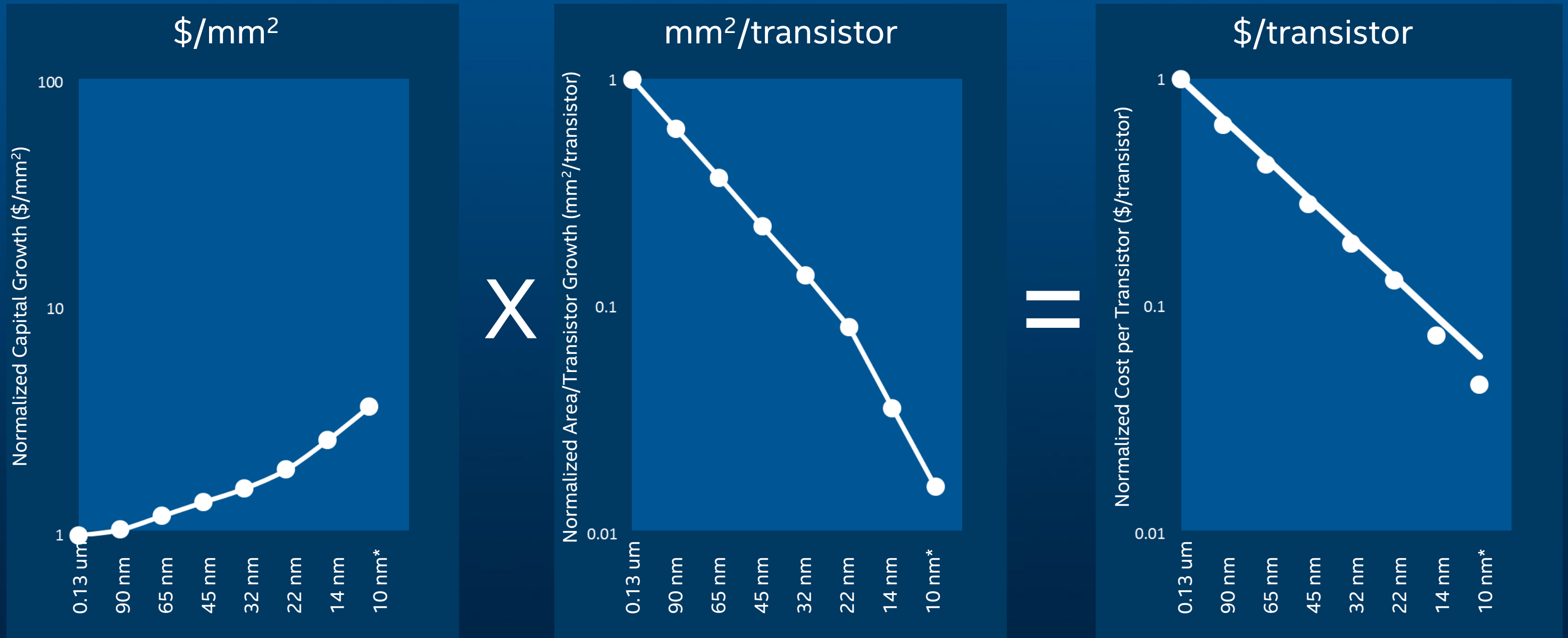
Broadwell delivers:

- 2.2x increase in transistor density
- Up to 40% better 3D graphics perf¹
- Enables <9mm fanless designs

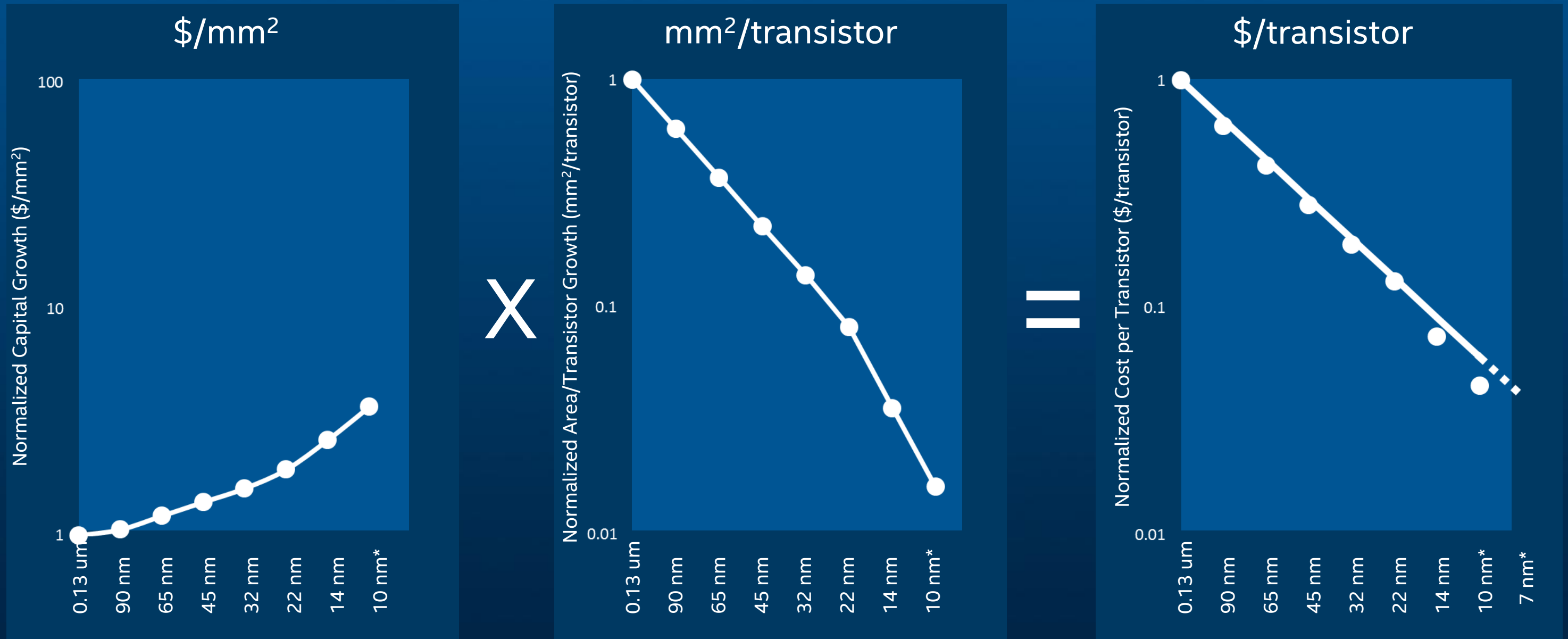
Industry's First 14 nm Processor in Volume Production

¹ Intel® Core™ M-5Y70 processor compared to Intel® Core™ i5-4302Y processor

Cost Reduction On Track



Cost Reduction On Track



Summary

Intel Continues to Deliver Moore's Law

True Cost Reduction Remains Possible

Technology Enables Real Product Improvements

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Risk Factors

The statements in the presentations and other commentary that refer to plans and expectations for the fourth quarter, the year and the future are forward-looking statements that involve a number of risks and uncertainties. Words such as “anticipates,” “expects,” “intends,” “plans,” “believes,” “seeks,” “estimates,” “may,” “will,” “should” and their variations identify forward-looking statements. Statements that refer to or are based on projections, uncertain events or assumptions also identify forward-looking statements. Many factors could affect Intel's actual results, and variances from Intel's current expectations regarding such factors could cause actual results to differ materially from those expressed in these forward-looking statements. Intel presently considers the following to be important factors that could cause actual results to differ materially from the company's expectations.

- Demand for Intel's products is highly variable and could differ from Intel's expectations due to factors including changes in the business and economic conditions; consumer confidence or income levels; customer acceptance of Intel's and competitors' products; competitive and pricing pressures, including actions taken by competitors; supply constraints and other disruptions affecting customers; changes in customer order patterns including order cancellations; and changes in the level of inventory at customers.
- Intel's gross margin percentage could vary significantly from expectations based on capacity utilization; variations in inventory valuation, including variations related to the timing of qualifying products for sale; changes in revenue levels; segment product mix; the timing and execution of the manufacturing ramp and associated costs; excess or obsolete inventory; changes in unit costs; defects or disruptions in the supply of materials or resources; and product manufacturing quality/yields. Variations in gross margin may also be caused by the timing of Intel product introductions and related expenses, including marketing expenses, and Intel's ability to respond quickly to technological developments and to introduce new features into existing products, which may result in restructuring and asset impairment charges.
- Intel operates in highly competitive industries and its operations have high costs that are either fixed or difficult to reduce in the short term.
- The declaration and rate of dividend payments and the amount and timing of Intel's stock buyback program are at the discretion of Intel's board of directors, and plans for future dividends and stock buy backs and could be affected by changes in Intel's priorities for the use of cash, such as operational spending, capital spending, acquisitions, and because of changes to Intel's cash flows and changes in tax laws.
- Intel's expected tax rate is based on current tax law and current expected income and may be affected by the jurisdictions in which profits are determined to be earned and taxed; changes in the estimates of credits, benefits and deductions; the resolution of issues arising from tax audits with various authorities, including payment of interest and penalties; and the ability to realize deferred tax assets.
- Gains or losses from equity securities and interest and other could vary from expectations depending on gains or losses on the sale, exchange, change in the fair value or impairments of debt and equity investments; interest rates; cash balances; and changes in fair value of derivative instruments.
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- Intel's results could be affected by the timing of closing of acquisitions, divestitures and other significant transactions.
- Intel's results could be affected by adverse effects associated with product defects and errata (deviations from published specifications), and by litigation or regulatory matters involving intellectual property, stockholder, consumer, antitrust, disclosure and other issues. An unfavorable ruling could include monetary damages or an injunction prohibiting Intel from manufacturing or selling one or more products, precluding particular business practices, impacting Intel's ability to design its products, or requiring other remedies such as compulsory licensing of intellectual property.

A detailed discussion of these and other factors that could affect Intel's results is included in Intel's SEC filings, including the company's most recent Form 10-Q, Form 10-K and earnings release.

Configuration Information

- Intel® Core™ M-5Y70 Processor (up to 2.60GHz, 4T/2C, 4M Cache) On Intel Reference Platform. BIOS: v80.1 Graphics: Intel® HD Graphics (driver v. 15.36.3650) Memory: 4 GB (2x2GB) Dual Channel LPDDR3-1600 SDD: Intel® 160GB OS: Windows* 8.1 Update RTM
- Prior generation: Intel® Core™ i5-4302Y (up to 2.30GHz, 4T/2C, 3M Cache) on Intel Reference Platform. 4.5W Thermal Design Power. BIOS: WTM 137 Graphics : Intel® HD Graphics (driver v. 15.36.3650) Memory: 4 GB (2x2GB) Dual Channel LPDDR3-1600 SDD: Intel® 160GB OS: Windows* 8.1 Update RTM. System Power Management Policy: Balance Wireless: On and connected. Battery size assumption: 35WHr.



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SANTA CLARA NOVEMBER 20